March 1997

LM383/LM383A 7W Audio Power Amplifier

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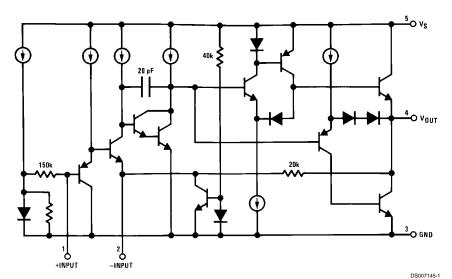
General Description

The LM383 is a cost effective, high power amplifier suited for automotive applications. High current capability (3.5A) enables the device to drive low impedance loads with low distortion. The LM383 is current limited and thermally protected. High voltage protection is available (LM383A) which enables the amplifier to withstand 40V transients on its supply. The LM383 comes in a 5-pin TO-220 package.

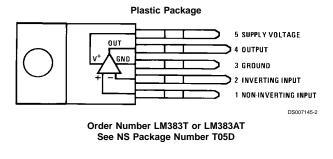
Features

- High peak current capability (3.5A)
- Large output voltage swing
- Externally programmable gain
- Wide supply voltage range (5V-20V)
- Few external parts required
- Low distortion
- High input impedance
- No turn-on transients
- High voltage protection available (LM383A)
- Low noise
- AC short circuit protected

Equivalent Schematic



Connection Diagram



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Absolute Maximum Ratings (Note *NO

TARGET FOR FNXref NS0064*),

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Peak Supply Voltage (50 ms)

 LM383A (Note 2)
 40V

 LM383
 25V

 Operating Supply Voltage
 20V

Output Current

 Repetitive
 3.5A

 Non-repetitive
 4.5A

 Input Voltage
 ±0.5V

 Power Dissipation (Note 3)
 15W

 Operating Temperature
 0°C to +70°C

 Storage Temperature
 -60°C to +150°C

 Lead Temperature
 -60°C to +150°C

(Soldering, 10 sec.) 260°C

Electrical Characteristics

 $\rm V_S$ = 14.4V, $\rm T_{TAB}$ = 25°C, $\rm A_V$ = 100 (40 dB), $\rm R_L$ = 4 Ω , unless otherwise specified

Parameter	Conditions	Min	Тур	Max	Units
DC Output Level		6.4	7.2	8	V
Quiescent Supply Current	Excludes Current in Feedback Resistors		45	80	mA
Supply Voltage Range		5		20	V
Input Resistance			150		kΩ
Bandwidth	Gain = 40 dB		30		kHz
Output Power	V _S = 13.2V, f = 1 kHz				
	$R_L = 4\Omega$, THD = 10%		4.7		W
	$R_L = 2\Omega$, THD = 10%		7.2		W
	$V_S = 13.8V, f = 1 \text{ kHz}$				
	$R_L = 4\Omega$, THD = 10%		5.1		W
	$R_L = 2\Omega$, THD = 10%		7.8		W
	$V_S = 14.4V, f = 1 \text{ kHz}$				
	$R_L = 4\Omega$, THD = 10%	4.8	5.5		W
	$R_L = 2\Omega$, THD = 10%	7	8.6		W
	$R_L = 1.6\Omega$, THD = 10%		9.3		W
	$V_{S} = 16V, f = 1 \text{ kHz}$				
	$R_L = 4\Omega$, THD = 10%		7		W
	$R_L = 2\Omega$, THD = 10%		10.5		W
	$R_{L} = 1.6\Omega$, THD = 10%		11		W
THD	$P_o = 2W$, $R_L = 4\Omega$, $f = 1$ kHz		0.2		%
	$P_o = 4W$, $R_L = 2\Omega$, $f = 1$ kHz		0.2		%
Ripple Rejection	$R_S = 50\Omega$, f = 100 Hz	30	40		dB
	$R_S = 50\Omega$, $f = 1 \text{ kHz}$		44		dB
Input Noise Voltage	R _S = 0, 15 kHz Bandwidth		2		μV
Input Noise Current	R_S = 100 kΩ, 15 kHz Bandwidth		40		pА

Note 1: A 0.2 μ F capacitor in series with a 1 Ω resistor should be placed as close as possible to pins 3 and 4 for stability.

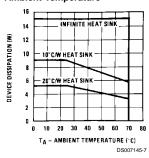
Note 2: The LM383 shuts down above 25V.

Note 3: For operating at elevated temperatures, the device must be derated based on a 150°C maximum junction temperature and a thermal resistance of 4°C/W junction to case.

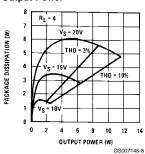
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Typical Performance Characteristics

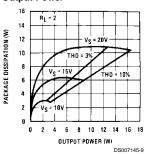
Device Dissipation vs Ambient Temperature



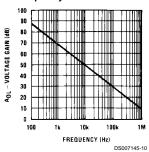
Power Dissipation vs Output Power



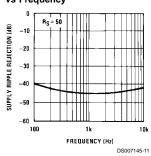
Power Dissipation vs Output Power



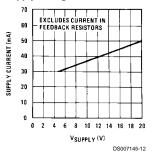
Open Loop Gain vs Frequency



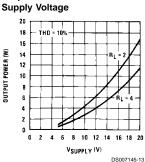
Supply Ripple Rejection vs Frequency



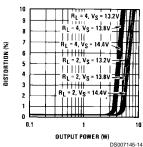
Supply Current vs Supply Voltage



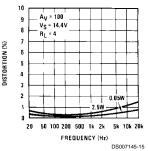
Output Power vs



Distortion vs Output Power



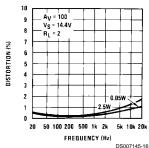
Distortion vs Frequency



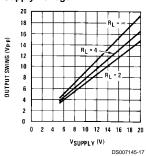
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Typical Performance Characteristics (Continued)

Distortion vs Frequency

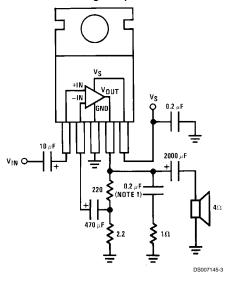


Output Swing vs Supply Voltage



Typical Applications

Single Amplifier

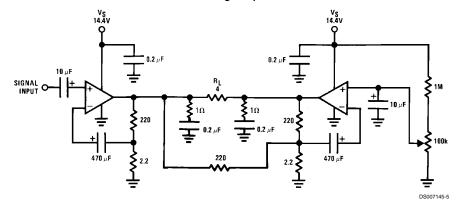


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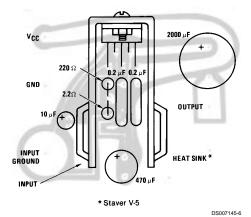
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Typical Applications (Continued)

16W Bridge Amplifier



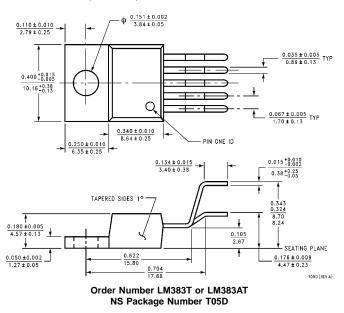
Component Layout



Single Amplifier $V_S = 20V$ $R_L = 4\Omega$ Heatsink from: Staver Company P.O. Drawer H Bay Shore, NY 11706 Tel: (516) 666-8000 Book Extract End

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Physical Dimensions inches (millimeters)



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